

HEXFRED® Ultrafast Soft Recovery Diode, 240 A



PRIMARY CHARACTERISTICS				
I _{F(AV)}	240 A			
V_{R}	400 V			
I _{F(DC)} at T _C	197 A at 100 °C			
Package	TO-244			
Circuit configuration	Two diodes common cathode			

FEATURES

- Very low Q_{rr} and t_{rr}
- UL approved file E222165





- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

BENEFITS

- Reduced RFI and EMI
- Reduced snubbing

DESCRIPTION / APPLICATIONS

HEXFRED® diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems. An extensive characterization of the recovery behavior for different values of current, temperature and dl_{F}/dt simplifies the calculations of losses in the operating conditions. The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for power converters, motors drives and other applications where switching losses are significant portion of the total losses.

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS	
Cathode to anode voltage	V _R		400	V	
Continuous forward current	I_	T _C = 25 °C	395		
Continuous forward current	l _F	T _C = 100 °C	197 A	Α	
Single pulse forward current	I _{FSM}	Limited by junction temperature	900		
Non-repetitive avalanche energy	E _{AS}	L = 100 μH, duty cycle limited by maximum T _J	1.4	mJ	
Maximum power dissipation P _D		T _C = 25 °C	658	W	
		T _C = 100 °C	263	¬	
Operating junction and storage temperature range	T _J , T _{Stg}		-55 to +150	°C	

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
Cathode to anode breakdown voltage	V _{BR}	I _R = 100 μA		400	-	-	
		I _F = 120 A		-	1.1	1.47	V
Maximum forward voltage	V_{FM}	I _F = 240 A	See fig. 1	=.	1.3	1.5	
		I _F = 120 A, T _J = 125 °C		-	1.0	1.2	
Maximum reverse leakage current	I _{RM}	T _J = 125 °C, V _R = 400 V	See fig. 2	-	660	5000	μΑ
Junction capacitance	C _T	V _R = 200 V	See fig. 3	-	280	380	pF
Series inductance	L _S	From top of terminal hole to mounting plane		=.	6.0	-	nΗ



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNITS
	I _F = 1.0 A, dI _F		$I_F = 1.0 \text{ A}, dI_F/dt = 200 \text{ A/}\mu\text{s}, V_R = 30 \text{ V}$	ı	50	-	
Reverse recovery time See fig. 5	t _{rr}	T _J = 25 °C		ı	77	120	ns
ess lig. s		T _J = 125 °C	I _F = 140 A dI _F /dt = 200 A/µs	ı	290	440	
Peak recovery current	I _{RRM}	T _J = 25 °C		-	7.5	14	۸
See fig. 6		T _J = 125 °C		-	16	30	A
Reverse recovery charge	Q _{rr}	T _J = 25 °C	$V_{R} = 200 \text{ V}$	-	290	780	nC
See fig. 7		T _J = 125 °C	11	-	2300	6300] "
Peak rate of recovery current See fig. 8 dI _{(rec)M} /c	dI _{(rec)M} /dt	T _J = 25 °C		=	320	-	A/µs
		T _J = 125 °C		-	270	-	ΑνμS

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER Maximum junction and storage temperature range		SYMBOL T _J , T _{Stg}	MIN.	TYP.	MAX. 150	UNITS °C
			- 55			
Thermal registance innetion to come	per leg	- R _{thJC}	-	-	0.19	°C/W
Thermal resistance, junction to case	per module		-	-	0.095	
Typical thermal resistance, case to heatsink		R _{thCS}	-	0.10	-	
Weight			-	68	-	g
			-	2.4	-	oz.
Mounting torque (1)			30 (3.4)	-	40 (4.6)	
Mounting torque (1)	center hole		12 (1.4)	-	18 (2.1)	lbf · in (N · m)
Terminal torque			30 (3.4)	=	40 (4.6)] ('` ''')
Vertical pull			-	-	80	IInd in
2" lever pull			-	-	35	lbf · in

Note

⁽¹⁾ Mounting surface must be smooth, flat, free of burrs or other protrusions. Apply a thin even film or thermal grease to mounting surface. Gradually tighten each mounting bolt in 5 to 10 lbf · in steps until desired or maximum torque limits are reached

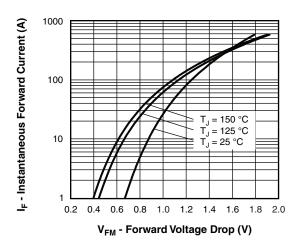


Fig. 1 - Maximum Forward Voltage Drop vs. Instantaneous Forward Current (Per Leg)

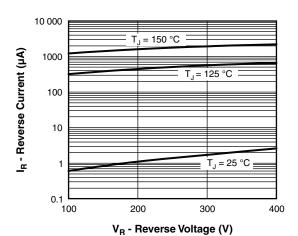


Fig. 2 - Typical Reverse Current vs. Reverse Voltage (Per Leg)

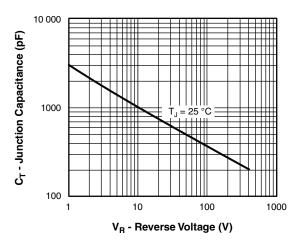


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

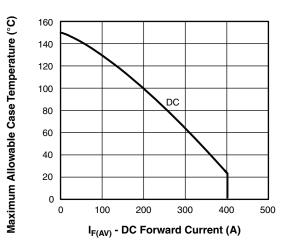


Fig. 4 - Maximum Allowable Case Temperature vs. DC Forward Current (Per Leg)

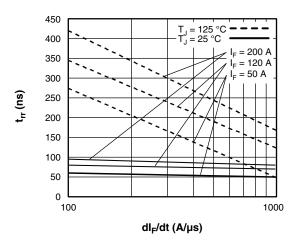


Fig. 5 - Typical Reverse Recovery Time vs. dl_F/dt (Per Leg)

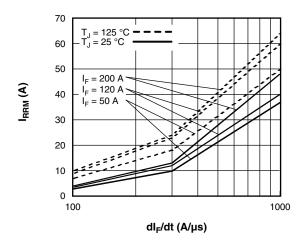


Fig. 6 - Typical Recovery Current vs. dI_F/dt (Per Leg)

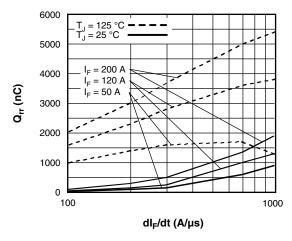


Fig. 7 - Typical Stored Charge vs. dl_F/dt (Per Leg)

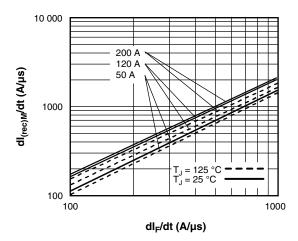


Fig. 8 - Typical dI_{(rec)M}/dt vs. dI_F/dt (Per Leg)

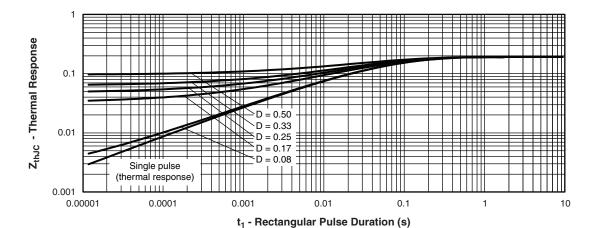


Fig. 9 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

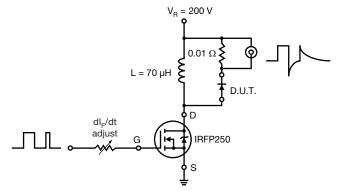
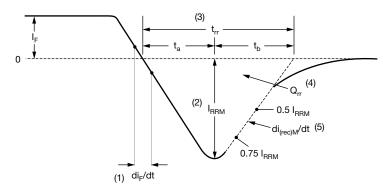


Fig. 10 - - Reverse Recovery Parameter Test Circuit



- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.
- (4) Q_{rr} area under curve defined by t_{rr} and I_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

(5) $di_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 11 - Reverse Recovery Waveform and Definitions



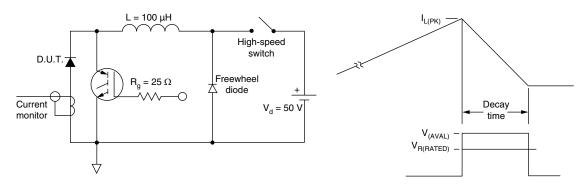
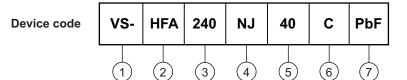


Fig. 12 - Avalanche Test Circuit and Waveforms

ORDERING INFORMATION TABLE



Vishay Semiconductors product

2 - HEXFRED® family, electron irradiated

3 - Average current rating

4 - NJ = TO-244

5 - Voltage rating (400 V)

6 - C = two diodes common cathode

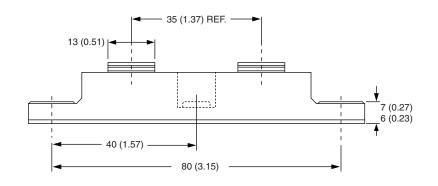
7 - Lead (Pb)-free

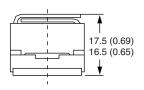
LINKS TO RELATED DOCUMENTS				
Dimensions <u>www.vishay.com/doc?95021</u>				

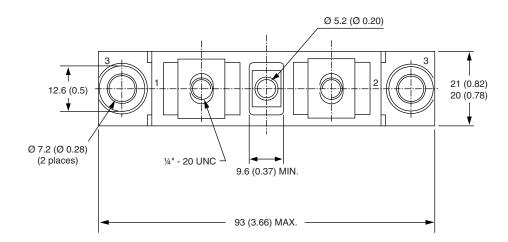


TO-244

DIMENSIONS in millimeters (inches)









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Vishay

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